

Absolute Maximum Ratings (@T_A = +25°C unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	150	V
Collector-Emitter Voltage	V _{CEO}	150	V
Emitter-Base Voltage	V _{EBO}	7	V
Continuous Collector Current	Ι _C	1	A
Peak Pulse Current	I _{CM}	3	A
Base Current	IB	500	mA

Thermal Characteristics (@T_A = +25°C unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Power Dissipation	(Note 6)	PD	3.8	W	
Thermal Resistance, Junction to Ambient	(Note 6)	R _{0JA}	33	°C/W	
Thermal Resistance, Junction to Leads	(Note 7)	R _{θJL}	12	°C/W	
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C	

ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

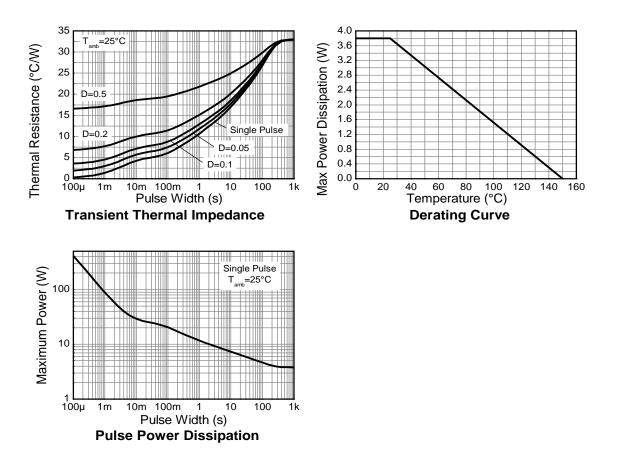
Notes: 6. For a device mounted with the exposed collector pad on 50mm x 50mm, 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.

7. Thermal resistance from junction to solder-point (on the exposed collector pad).

8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics and Derating Information





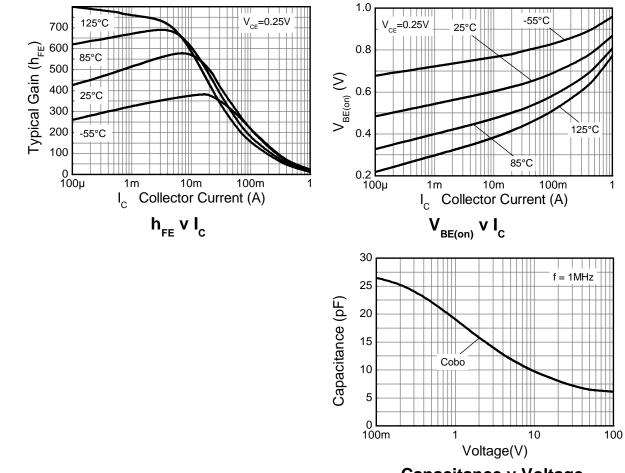


Electrical Characteristics (@T _A = +25°C unless otherwise specified						
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage (Note 9)	BV _{CBO}	150	-	-	V	$I_{\rm C} = 0.1 {\rm mA}$
Collector-Emitter Breakdown Voltage (Note 9)	BV _{CEO}	150	175	-	V	$I_{\rm C} = 10 {\rm mA}$
Emitter-Base Breakdown Voltage (Note 9)	BV _{EBO}	7	-	-	V	I _E = 0.1mA
Collector – Emitter Cut-off Current	I _{CES}	-	-	50	nA	V _{CE} = 150V
Collector Cut-off Current	ICBO	-	-	50	nA	V _{CB} = 150V
Emitter Cut-off Current	I _{EBO}	-	-	50	nA	V _{EB} = 7V
Static Forward Current Transfer Ratio (Note 9)	hFE	60 100	-	-	-	$I_{C} = 85mA, V_{CE} = 0.20V$ $I_{C} = 150mA, V_{CE} = 0.25V$
Collector-Emitter Saturation Voltage (Note 9)	V _{CE(sat)}	-	-	0.25	V	$I_{\rm C} = 100 {\rm mA}, I_{\rm B} = 5 {\rm mA}$
Base-Emitter Saturation Voltage (Note 9)	V _{BE(sat)}	-	-	0.95	V	$I_{\rm C} = 100 {\rm mA}, I_{\rm B} = 5 {\rm mA}$
Base-Emitter Turn-On Voltage (Note 9)	V _{BE(on)}	-	0.71	0.95	V	I _C = 150mA, V _{CE} = 0.25V
Delay Time	t _(d)	-	512	-	ns	
Rise Time	t(r)	-	426	-	ns	$V_{CC} = 120V, I_{C} = 150mA,$
Storage Time	t _(s)	-	3413	-	ns	-I _{B2} = 1.5mA, V _{CE} (_{ON}) = 0.25V
Fall Time	t _(f)	-	321	-	ns	
Storage Time	t _(s)	-	65	-	ns	V _{CC} = 120V, I _C = 150mA,
Fall Time	t _(f)	-	294	-	ns	$-I_{B2} = 1.5 \text{mA}, V_{CE}(ON) = 4 \text{V}$

Note: 9. Measured under pulsed conditions. Pulse width = 300μ s. Duty cycle $\leq 2\%$.



Typical Electrical Characteristics

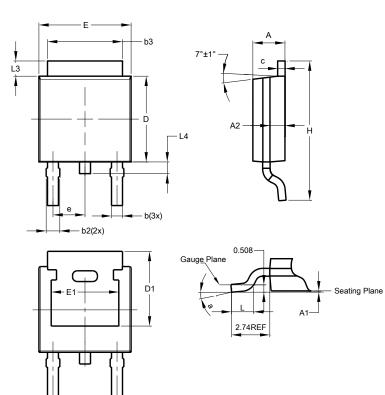


Capacitance v Voltage



Package Outline Dimensions

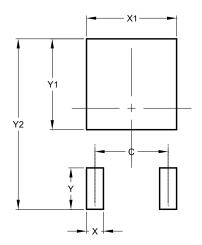
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



	TO252 (DPAK)				
Dim	Min	Max	Тур		
Α	2.19	2.39	2.29		
A1	0.00	0.13	0.08		
A2	0.97	1.17	1.07		
b	0.64	0.88	0.783		
b2	0.76	1.14	0.95		
b3	5.21	5.46	5.33		
С	0.45	0.58	0.531		
D	6.00	6.20	6.10		
D1	5.21	-	-		
е	-	-	2.286		
Ε	6.45	6.70	6.58		
E1	4.32	-	-		
Н	9.40	10.41	9.91		
L	1.40	1.78	1.59		
L3	0.88	1.27	1.08		
L4	0.64	1.02	0.83		
а	0°	10°	-		
All Dimensions in mm					

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)			
С	4.572			
Х	1.060			
X1	5.632			
Y	2.600			
Y1	5.700			
Y2	10.700			



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